## NSN 5961-01-174-1076

Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Plastic
Overall Length:
0.785 inches
Terminal Length:
0.135 inches
Overall Height:
0.200 inches
Overall Width:
0.250 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-116
Component Name And Quantity:
4 transistor
Mounting Method:
Terminal
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
60.0 collector to base voltage, dc all transistor and 40.0 collector to emitter voltage, dc all transistor and 5.0 emitter to base voltage, dc all
transistor
Current Rating Per Characteristic:
50.00 milliamperes collector current, dc all transistor
Power Rating Per Characteristic:
1.5 watts total power dissipation all transistor
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
All transistor junction pattern arrangement: pnp
Terminal Type And Quantity:
14 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0